



M T B F

(E I A J R C R - 9 1 0 2)

Model	LEA50F-12
-------	-----------

No.	P a r t s		Q' ty of Device	Failure rate [10 ⁻⁶ /H]	Reference
1	I C	Monolithic	3	0.1060	
2		Hybrid	0	0.0000	
3	Transistors		6	0.3003	
4	Diodes		19	0.4070	
5	LED•Optocouplers		2	0.1400	
6	Resistors		82	0.4602	
7	Capacitors		31	0.3460	
8	Transformer•Choke Coil		8	0.1219	
9	Connectors		368	0.1908	
10	Others		5	0.0880	
Total Failure Rate [10 ⁻⁶ /H]				2.1602	

M T B F	[H]	463,000
Ambient Temperature	[°C]	—
Load Factor	[%]	—